

10/069456

[20103/00201]

DECLARATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am an original, first (if only one name is listed below) and joint inventor (if multiple names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled **DEVICE FOR FORMING NANOSTRUCTURES ON THE SURFACE OF A SEMICONDUCTOR WAFER BY MEANS OF ION BEAMS**, for which an application for Letters Patent was filed as PCT International Application Number **PCT/RU01/00261** on July 2, 2001.

PRIOR FOREIGN APPLICATION(S)

I hereby claim foreign priority benefits under Title 35, United States Code, §§ 119(a)-(d) and 172, of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificated having a filing date before that of the application on which priority is claimed:

PRIOR FOREIGN APPLICATION(S)

Number	Country filed	Day/month/year	Priority Claimed Under 35 USC 119
2000117335	Russian Federation	4 July 2000	Yes

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims.

I acknowledge the duty to disclose information which is material to the examination of this

application in accordance with Title 37, Code of Federal Regulations,
§ 1.56(a).

Please address all communications regarding this application to:

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Please direct all contacts to Oleg F. Kaplun at (212) 898-8819 or via email at
okaplun@fkmiplaw.com.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful and false statements may jeopardize the validity of the application or any patent issued thereon.

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Inventor's Signature: D. Kibalov / KIBALOV D.S.

Date: 20 March 2002

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